

Attorney's Docket No.:07977/017002

REMARKS

Reconsideration and allowance of the above referenced application are respectfully requested.

Claims 1-2,4,5,7-11, 22, 23, 28-32, 35, 36, 43-47, 52-55, 61-86 stand rejected under 35 USC 103 as allegedly being anticipated by Zhang. In response, applicants herewith amend claims 1, 22, 43 and 52 to recite forming a gate electrode over the insulating film. Claim 65 and 74 are amended to recite that the portion to which the impurity element is introduced, constitutes a channel region of the thin film transistor. These amendments clarify that the claimed ion doping process is directed to a channel doping process for controlling threshold voltage. This distinguishes from Zhang's ion implantation process for forming source and drain regions after forming a gate electrode, as described column 10 lines 39-67. For these reasons, it is respectfully suggested that these amendments overcome the rejection.

In view of the above amendments and remarks, therefore, all of the claims should be in condition for allowance. A formal notice to that effect is respectfully solicited.

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Please apply \$410.00 for the two month extension fee and
any other charges or credits to Deposit Account No. 06-1050.

Respectfully submitted,

Date: 05/30/03



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